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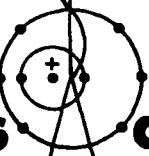
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Low-Temperature Equation of State for Metals

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Low-Temperature Equation of State for Metals

by

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LOW-TEMPERATURE EQUATION OF STATE FOR METALS

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ABSTRACT

A code has been developed that calculates an improved equation of state (EOS) for pure metals in the melt-vapor region. The theory behind the code incorporates contributions to the EOS from a zero temperature model as well as from thermal atomic and electronic calculations, but does not include the effects of polymorphic and higher-order phase transitions. Pressures and energies have been obtained for several metals with Z less than 26 over temperature ranges from 0.02 eV to 10 keV and densities from 10^{-26} g cm $^{-3}$ to 1000 g cm $^{-3}$. Comparison of calculated critical point parameters (temperature, pressure, and density) with experiment is difficult due to scarcity of experimental results, but such comparisons tend to show the calculated values to be too large, a feature shared with other theoretical results.

I. INTRODUCTION

Many applications require consistent and reasonably accurate equation-of-state (EOS) results over a large range of temperatures and densities. For temperatures above 10^5 K, adequate results are obtained from existing codes, but below those temperatures and at normal densities the codes are not able to handle the calculations in the melt-vapor region. Usually ideal gas conditions are assumed. This code was developed to obtain more accurate pressures and internal energies for pure metals in this mixed-phase region. The present version of the code is able to calculate this first-order phase transition, but cannot handle polymorphic or higher-order phase transitions. For this reason, metals such as iron and titanium cannot be accurately calculated at this time.

The pertinent aspects of the problem can be seen in Fig. 1. Three isotherms, T_1 , T_2 , and T_3 , are shown on this P-V diagram, where T_2 and T_3 pass through the melt-vapor region shown by the dotted line and T_1 lies above it. Most existing codes produce isotherms similar to T_1 for all temperatures

T_1 , T_2 , and T_3 and ignore the distortion of the pressure curve due to the presence of the mixed-phase region. Using more realistic models, especially for

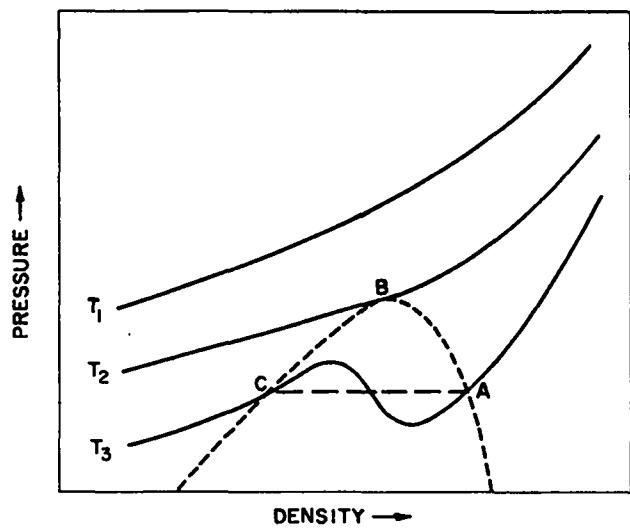


Fig. 1. Typical P-V diagram showing location of mixed-phase region.

the $T = 0$ calculation, resulted in the actual isotherm T_3 . By thermodynamic considerations, the stable path of the system through the mixed-phase region is not the isotherm T_3 , but rather the dashed line from A to C, where A and C are local minimum of the Gibbs free energy. Therefore, to obtain the EOS of the system it is necessary to calculate both the boundary of the mixed-phase region and the isotherm.

II. THEORY

As mentioned above, the contributions to the isotherm come from zero temperature and thermal effects. Obtaining the pressure and energy from the $T = 0$ curve is therefore the first step. The pressure curve was fitted to satisfy the experimental shock Hugoniot, the cohesive energy of the metal, and the ultimate tensile strength. The resultant curve, labeled P_c , is shown in Fig. 2, where P_H is the Hugoniot curve. This isotherm has been split into three regions for computational reasons, and the boundary conditions for each region are listed in Table I. In these equations, E_c is the cohesive energy, P_o is the ultimate tensile strength, S and C_o are obtained from the Hugoniot shock relationship shown in Eq. (1), and $P_c(125)$ comes from a Thomas-Fermi calculation.

$$U_s = C_o + S \cdot U_p \quad , \quad (1)$$

and

$$\delta = S/(1 + S) \quad . \quad (2)$$

TABLE I
 $T = 0$ ISOTHERM BOUNDARY CONDITIONS

<u>Physical Constraints</u>	<u>Region</u>		
	I	II	III
$P_c(125) = P_{TF}(125)$	x		
$P_c'(1) = 0$	x	x	
$P_c''(1) = P_H''(1) = 0.01P_oC_o^2$	x	x	
$P_c'''(1) = P_H'''(1) = 0.02P_oC_o^2(2S - 1)$	x	x	
$P_c(\delta) = -P_o$	x	x	
$P_c'(\delta) = 0$	x	x	
$P_c(0) = 0$		x	
$\int_1^0 P_c / \eta^2 d\eta = \rho_o E_c$	x	x	

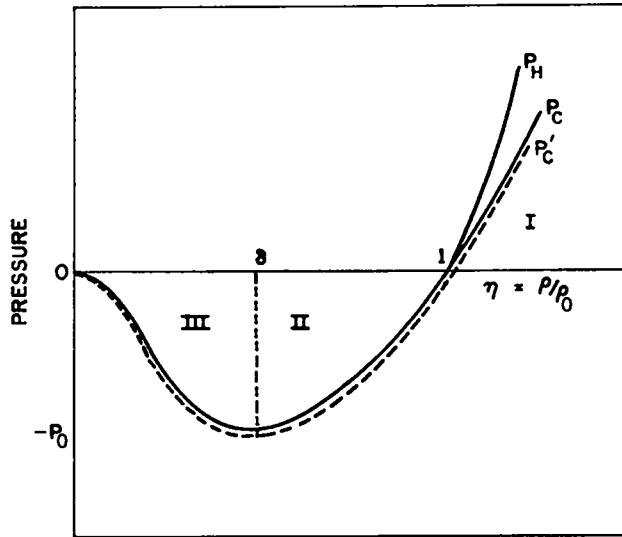


Fig. 2. Illustrative plot of the theoretical $T = 0$ curve P_c and the modified $T = 0$ curve P'_c .

The expression for P_c in region I is similar to the modified pressure function used by Barnes¹ and takes into account the attractive and repulsive nature of the interatomic forces. This formula is given in Eq. (3), where A , B_r , and B_a are derived from the boundary conditions.

$$\eta > 1$$

$$P_c = A\eta^{2/3} \left(\eta e_r^{\frac{B_r}{\eta}} - e_a^{\frac{B_a}{\eta}} \right) \quad , \quad (3)$$

$$\eta = 1 - \eta^{-1/3} \quad .$$

The expressions for P_c in the other two regions are derived entirely from the boundary conditions with the additional mathematical constraint that $dP_c/d\eta \leq 0$ in region III. The negative portion of the curve was split after mathematical difficulties were encountered in treating it as one region. The resultant equations are

$$\delta \leq \eta \leq 1$$

$$P_c = \eta^{4/3} (\eta^{1/3} - 1) \left[A + (\eta^{1/3} - \delta^{1/3}) \left[B + (\eta^{1/3} - \delta^{1/3}) \left[C + (\eta^{1/3} - 1) [D + (\eta^{1/3} - 1) E] \right] \right] \right] \quad (4)$$

and

$$\eta < \delta$$

$$P_c = P_0 [K + 2 - (K + 1)\eta/\delta] (\eta/\delta)^{(K+1)} \quad . \quad (5)$$

After the pressure is obtained, the energy contribution can be calculated easily from the relationship

$$\frac{1}{P_0} \int_1^x \frac{P_c}{\eta^2} d\eta = E_{cold} \quad . \quad (6)$$

As a partial check on the calculation, it is possible to use the P_c curve for $\eta \geq 1$ to recalculate the Hugoniot curve and to compare it to experimental results. The relationship between P_H and P_c is given in Eq. (7),

$$P_H = (P_c - \rho_0 \gamma \eta E_c) / (1 - \gamma(n-1)/2) \quad . \quad (7)$$

where γ is the Gruneisen ratio and is obtained from

$$\gamma = -\frac{1}{3} + \frac{1}{2} \frac{\eta^2 P_c'' + 2/3 \eta P_c' - 2/9 P_c}{\eta P_c' - 2/3 P_c} \quad . \quad (8)$$

Plots of the resultant P_H curves are shown in Fig. 3 where the experimental points are from averaged curves.^{2,3} As expected, comparison is quite good at normal and higher densities, well within experimental error.

For temperatures greater than zero, contributions to the pressure, energy, and entropy arise from atomic and electronic components. At present, treatment of the atomic EOS is similar to that used by Thompson,⁴ which in turn is based on the work of Kormer et al.⁵ Without going into detail, the important equations are given below.

$$F_n = N_o kT [3\ln(\theta/T) - 1 + 1.5\ln(1+\Psi)] \quad , \quad (9)$$

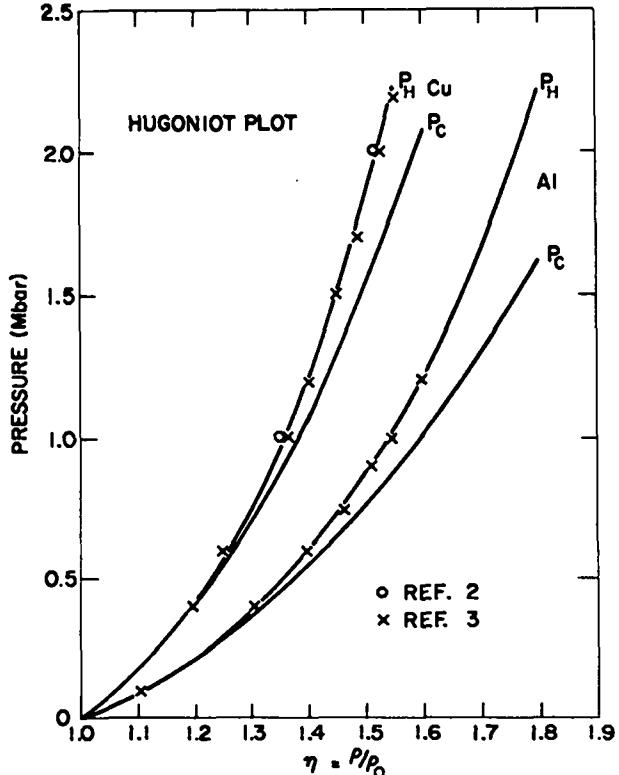


Fig. 3. Comparison of experimental and theoretical Hugoniot curves.

$$P_n = \rho N_o kT \left[\frac{3\Gamma + \Psi}{1 + \Psi} \right] \quad , \quad (10)$$

$$E_n = 1.5 N_o kT \left[\frac{2 + \Psi}{1 + \Psi} \right] \quad , \quad (11)$$

$$S_n = -N_o k [3\ln(\theta/T) - 4 + 1.5\ln(1 + \Psi) + 1.5\Psi/(1 + \Psi)] \quad , \quad (12)$$

and

$$\Psi = F(\rho, T) \quad .$$

F_N is the nuclear-free energy and P_N , E_N , and S_N are the pressure, energy, and entropy, respectively, obtained by the normal thermodynamic relationships from F_N . θ is the Debye temperature and Γ is the Gruneisen ratio, both functions of density. Ψ is an interpolation function that transforms the equations smoothly from high to low temperatures and gives rise to a continuous if somewhat inaccurate transition for P_N , E_N , and S_N . This is necessary

for the numerical methods used in the code. Table II shows the rapid variation of Ψ with density for aluminum at a constant temperature.

The electronic thermal contribution is a Thomas-Fermi-like treatment, but uses a modified and parameterized Thomas-Fermi potential to speed up the calculations. This potential, broken into two parts, is

$$0 < r < r_1$$

$$\Psi(r) = Ze/(1 + \alpha r)^2/r + Z^* e(r^2/2R^2 - B_0)/R \quad (13)$$

$$B_0 = (Z/Z^*)^2 (R/r_1)/(1 + \alpha r_1)^2 - R/r_1 + 1.5 \quad (14)$$

$$\alpha = 0.6057 Z^{1/3} \quad , \quad (15)$$

and

$$r_1 < r < R$$

$$\Psi(r) = Z^* e(R/r + r^2/2R^2 - 1.5)/R \quad . \quad (16)$$

R is the radius of the spherical atomic volume, r_1 is the radius at which Eqs. (9) and (10) join, Z^* is the "effective number" of free electrons, and e is the electronic charge. Z^* is calculated using

TABLE II
REPRESENTATIVE VALUES OF
INTERPOLATION FUNCTION

$n = \rho/\rho_0$	Ψ
0.05	137.01
0.1	40.88
0.2	9.50
0.3	3.70
0.4	1.489
0.5	0.7459
0.6	0.4135
0.7	0.2494
0.8	0.1621

Fermi-Dirac statistics for the electronic distribution. With this information, P_{el} and E_{el} can be found with the equations

$$P_{el} = (2/3\rho) \left(I_{3/2}(\mu)/I_{1/2}(\mu) \right) kT \quad , \quad (17)$$

$$E_{el} = (3P_e/\rho + E_S/2) \quad . \quad (18)$$

The electronic Gibbs free energy is

$$G_{el} = -\mu N \quad . \quad (19)$$

$I_{1/2}$ and $I_{3/2}$ are the Fermi-Dirac integrals of order 1/2 and 3/2 and E_S is the electronic interaction energy. N is the number of free electrons and μ is the electron degeneracy parameter.

III. CALCULATIONS AND RESULTS

Although the theory has now been fully outlined, several important boundary conditions must be established before the actual calculations can be undertaken. First, the electronic model does not approach zero pressure or internal energy as $T \rightarrow 0$, therefore a zero temperature reference point must be chosen. The temperature 0.01 eV was picked as the pressure, etc., had become essentially constant for all lower temperatures. To remain consistent, it was necessary to use the same reference point for the nuclear model. Thus, for example, the total pressure would now become

$$\begin{aligned} P_{Tot}(T) &= P_{el} + P_N + P_c \\ &= P_c + [P_{el}(T) - P_{el}(0.01)] \\ &\quad + [P_N(T) - P_N(0.01)] \quad . \quad (20) \end{aligned}$$

Next, the $T = 0$ curve is based on Hugoniot parameters, etc., obtained at ambient temperatures where there are thermal contributions to the EOS. Assuming this temperature to be 0.02 eV, the "cold" curve P_c in Fig. 2 actually includes some thermal effects. To take this into account, the pressure curve has been adjusted to give a total pressure of zero at normal density and 0.02 eV. Therefore, the P_c curve is the $T = 0.02$ eV curve, the true $T = 0$ curve ($P_{c,0}$) lies just below the P_c curve and crosses the horizontal axis at a density greater than normal density. This gives a slightly denser reference

density R_0 for the cold curve, consistent with the fact that a metal will contract slightly as it is cooled.

A final modification now must be made to the electronic model because it does not allow for the transition from a free electron gas to a solid. The model produces too large a contribution at low temperatures and therefore has been multiplied by

$$G(T, \rho) = 2 / \left[1 + \exp \left(\left(10 - 10 / (1 + \Psi) \right) / T \right) \right] , \quad (21)$$

which reduces the electronic EOS below 5.0 eV. Ψ is the same as in the nuclear model and the coefficient 10 was chosen as an average ionization energy for the light metals. Thus, the final electronic pressure is now

$$P_{el} = G(T, \rho) [P_{el}(T) - P_{el}(0.01)] . \quad (22)$$

As mentioned previously, the pressure and Gibbs free energy were used to define the mixed-phase region. With the above modifications, these quantities can now be defined.

$$\begin{aligned} P_{Tot} &= P_c + [P_N(T) - P_N(0.01)] \\ &+ G(T, \rho) [P_{el}(T) - P_{el}(0.01)] , \end{aligned} \quad (23)$$

$$\begin{aligned} G_{Tot} &= E_c + [E_N(T) - E_N(0.01)] \\ &+ \left[P_c + (P_N(T) - P_N(0.01)) \right] / \rho \\ &- [T S_N(T) - 0.01 S_N(0.01)] \\ &+ G(T, \rho) [G_{el}(T) - G_{el}(0.01)] . \end{aligned} \quad (24)$$

Looking at Fig. 1 again, the logical place to start the calculations is the critical point, where the T_2 isotherm just passes through the melt-vapor region. This point is located by finding the zero

points of the first and second derivatives of the pressure with respect to density. In approaching the critical point, extreme care must be exercised to remain below the critical temperature and above the critical density during the search to ensure convergence. Comparison of the calculated critical point parameters to those of other theoretical models and experiment is outlined in Table III.

When the critical point has been established, the other boundary points (A and C in Fig. 1) are found by simultaneously equating the Gibbs free energy and the pressure at the upper and lower densities. Expanding Eqs. (23) and (24) in first-order Taylor series, we obtain the calculational technique used to determine the correct densities.

$$\begin{pmatrix} P(\eta_2) - P(\eta_1) \\ G(\eta_2) - G(\eta_1) \end{pmatrix} = \begin{pmatrix} \partial P_1 / \partial \eta_1 & \partial P_2 / \partial \eta_2 \\ \partial G_1 / \partial \eta_1 & \partial G_2 / \partial \eta_2 \end{pmatrix} \begin{pmatrix} \Delta \eta_1 \\ \Delta \eta_2 \end{pmatrix} . \quad (25)$$

After the boundary is set up, the isotherms can be calculated easily for the metal. Outside the mixed-phase region, the pressure and energy are calculated normally as outlined in previous sections. Inside the mixed-phase region, the pressure is a constant (equal to the value on the boundary) whereas the energy is a linear interpolation between the values at the upper and lower densities. The mixed-phase region and representative isotherms are shown for aluminum and beryllium in Figs. 4 and 5. A sample input and output is provided in Appendix A for users, whereas the code is listed in Appendix B.

IV. DISCUSSION OF RESULTS

Table III shows that the calculated temperatures and pressures are consistently higher than the experimental values for the few elements that can be compared. This is to be expected for our calculations because the experimental results are for the soft metals, whereas the electronic effects are relatively more important than for other metals. Thus, our modification of the present thermal electronic model plus our present inability to separate out the electronic effects in the cohesive energy and Hugoniot parameters leads to the overly high values. We hope that this discrepancy will be reduced when the electronic model is improved in the

next version of the code where a more accurate quantum theory using the method of quantum defects will be employed instead of the present model. The effect of the thermal electronic effect on the $T = 0$ isotherm parameters (cohesive energy, Hugoniot parameters, etc.) will also be examined in more detail.

In spite of the above difficulties, the code is a useful one for two reasons. First, it is quite general and is able to produce useful results for most metals below $Z = 30$ with only eight input parameters. Second, the calculated isotherms are consistent for all densities and all temperatures above 0.01 eV, and although somewhat inaccurate in the immediate vicinity of the critical point, they are quite accurate for most of the solid and vapor regions. Thus, we hope that users will find the code helpful while an updated version is being prepared.

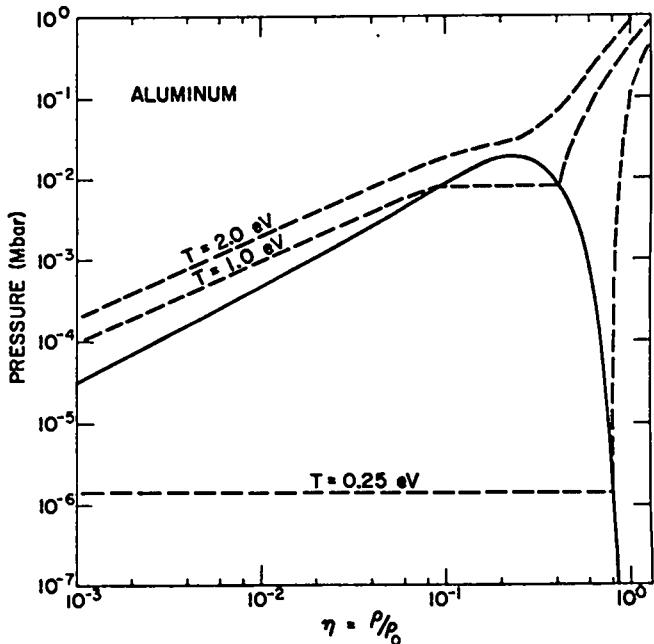


Fig. 4. Detailed plot of aluminum mixed-phase region and representative isotherms.

TABLE III
CRITICAL POINT PARAMETER COMPARISON

Element	LTEOS	Thompson ^{4,7}	Grosse ⁸	Adler & Young ⁶	Experimental ^b Results
Lithium	$T_c = 0.5351 \text{ eV}$		0.3541	0.3301	0.2777 ± 0.052
	$P_c = 0.00184 \text{ Mbars}$			0.002422	0.000689 ± 0.00014
	$\rho_c = 0.071 \text{ gcm}^{-3}$			0.1470	0.1148 ± 0.0332
Beryllium	$T_c = 0.919$	0.785			
	$P_c = 0.0330$	0.0142			
	$\rho_c = 0.577$	0.318			
Sodium	$T_c = 0.5730$		0.2413	0.2270	0.2217 ± 0.03
	$P_c = 0.00202$		0.0004965	0.000921	0.000355 ± 0.00007
	$\rho_c = 0.1947$		0.1796	0.2692	0.2025 ± 0.04
Magnesium	$T_c = 0.7218$		0.3317	0.2937	
	$P_c = 0.0680$		0.00175	0.001929	
	$\rho_c = 0.7908$		0.4122	0.4615	
Aluminum	$T_c = 1.479$	0.904	0.7367	0.6162	
	$P_c = 0.0188$	0.00616		0.005458	
	$\rho_c = 0.679$	0.478		0.690	
Copper ^a	$T_c = 1.951$		0.7667	0.6570	
	$P_c = 0.0382$			0.0083	
	$\rho_c = 2.323$		1.048	2.318	

^aConverged on critical point, but did not converge on mixed-phase boundary.

^bExtrapolated to critical temperature from experimental data.⁹

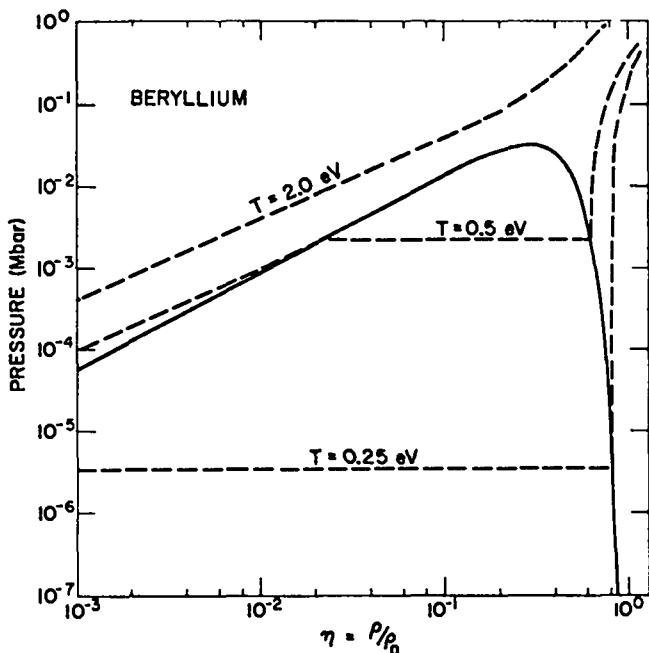


Fig. 5. Detailed plot of beryllium mixed-phase region and representative isotherms.

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APPENDIX A SAMPLE CALCULATIONS FOR BERYLLIUM

INPUT FORMAT FOR LTEOS CODE

Card #1 (8F10.8)

Column	Symbol	Identification
1-10	ATMNO	Atomic number of element
11-20	ATMW	Atomic weight of element
21-30	R0	Normal density
31-40	S	Hugoniot S
41-50	C0	Hugoniot C ₀
51-60	P0	Tensile strength
61-70	U	Cohesive energy
71-80	H4	Debye temperature

Card #2 (2I4)

Column	Symbol	Identification
1-4	NTHETA	Number of temperature points*
5-8	NRHO	Number of density points

* Note—if zero, go to next element.

Card #3 (6E12.5)

List all temperature points, if any, in the above format.

Card #4 (6E12.5)

List all density points in the above format.

III. OUTPUT FROM LTEOS

INPUT PARAMETERS					
ATOMIC NUMBER	= 4.00000E+00	NORMAL DENSITY(GM/GM3)	= 1.0510CE+00		
ATOMIC WEIGHT	= 9.01300E+00	CALC DENSITY(GM/GM3)	= 1.0624SE+00		
MOLAR MASS	= 1.12400E+00	COHESIVE ENERGY(LEVEL)	= 3.60CCCE-01		
HUGENCHET CO	= 7.99800E+00	TENSILE STRENGTH(MBARS1)	= -2.6112E-01		
		PRESSURE(PETA1231MBARS1)	= 1.61C68E+04		
		DEBYE TEMPERATURE(LEVEL)	= 9.9950CE-02		
<hr/>					
T = 0 ISOTHERM CALCULATIONS					
GRIESEL CAPMA	= 1.24800E+00				
MAXIMUM PRESSURE LOCATION(LEVEL)	= 01 = 5.29190E-01				
<hr/>					
ELASTIC CONSTANTS					
ETA LESS THAN CI	-----K = 2.06105E+00				
ETA BETWEEN CI AND 1.-C1	= 3.27719E+00				
C2	= 9.30464E-01				
C3	= 3.22963E+00				
C4	= 1.33117E+01				
C5	= -9.52017E-01				
ETA GREATER THAN 1.----A	= 1.06111E+00				
BR	= 1.9830AT+00				
SA	= 1.61437E+00				
<hr/>					
CHEMICAL POINT RESULTS					
T-GRIT+EVI	= 9.1872229E-01				
P-C1193P451	= 3.297336AE-02				
ETA-CHIT	= 3.1165838E-01				
<hr/>					
FIXED PHASE BOUNDARY PARAMETERS					
TEMPERATURE LEVEL	ETA	PRESSURE 1MBAR1	ENERGY 1MBAR1-CC/GM1	GBHS ENERGY	
8.50000E-01	1.69901E-01	2.38846E-02	4.90417E-01	-7.78167E-01	
	4.18183E-01	2.38846E-02	3.99695E-01	-7.78167E-01	
8.00000E-01	1.36211E-01	1.91285E-02	4.86963E-01	-7.15150E-01	
	4.63664E-01	1.91285E-02	3.64480E-01	-7.15150E-01	
7.50000E-01	1.09190E-01	1.50191E-02	4.81107E-01	-6.52694E-01	
	4.95180E-01	1.50191E-02	3.36359E-01	-6.52694E-01	
7.00000E-01	8.66688E-02	1.14631E-02	4.74144E-01	-5.91027E-01	
	5.20803E-01	1.14630E-02	3.11048E-01	-5.91027E-01	
6.50000E-01	6.95349E-02	8.68340E-03	4.66471E-01	-5.28294E-01	
	5.43805F-01	8.68340E-03	2.88833E-01	-5.28294E-01	
6.00000E-01	5.09562E-02	5.94728E-03	4.58289E-01	-4.7C15AE-01	
	5.68797E-01	5.94728E-03	2.63212E-01	-4.7C15AE-01	
5.50000E-01	3.62457E-02	3.89026E-03	4.45893E-01	-4.11919E-01	
	5.97712E-01	3.89026E-03	2.38036E-01	-4.11919E-01	
5.00000E-01	2.33067E-02	2.26903E-03	4.41425E-01	-3.56427E-01	
	6.30227E-01	2.26903E-03	2.11430E-01	-3.56427E-01	
4.50000E-01	1.34442E-02	1.17102E-03	4.33092E-01	-3.02165E-01	
	6.66239E-01	1.17102E-03	1.85513E-01	-3.02165E-01	
4.00000E-01	6.50173E-03	5.02442E-04	4.24942E-01	-2.5C157E-01	
	7.05109E-01	5.02442E-04	1.60163E-01	-2.5C157E-01	
3.50000E-01	2.32688E-03	1.56810E-04	4.16R94E-01	-2.02286E-01	
	7.45954E-01	1.56809E-04	1.34353E-01	-2.02286E-01	
3.00000E-01	5.73357E-04	3.29620E-05	4.08862E-01	-1.56172E-01	
	7.87749E-01	3.29619E-05	1.11725E-01	-1.56172E-01	
2.50000E-01	6.95819E-05	3.31060E-06	4.0C830E-01	-1.14614E-01	
	8.29417E-01	3.31060E-06	0.86467E-02	-1.14614E-01	
2.00000E-01	2.49947E-06	9.41457E-08	3.92797E-01	-7.6600E-02	
	8.70076E-01	9.41457E-08	6.75465E-02	-7.6600E-02	
1.50000E-01	6.87346E-09	1.90767E-10	3.84765E-01	-4.4C4C4E-02	
	9.09061E-01	1.90767E-10	4.86730E-02	-4.4C4C4E-02	
1.00000E-01	1.8077AF-14	3.22543E-16	3.76732E-01	-1.7P157E-C2	
	9.45941E-01	3.22543E-16	3.03235E-02	-1.7P157E-C2	
7.50000E-02	1.40992E-20	1.81679E-22	3.72716E-01	-7.7C452E-03	
	9.63505E-01	1.81679E-22	2.16730E-02	-7.7C452E-03	
5.00000E-02	1.71580E-34	1.36058E-36	3.68700E-01	-6.53067E-04	
	9.80462E-01	1.36058E-36	1.31040E-02	-6.53067E-04	

APPENDIX B

LISTING OF THE LTEOS CODE

```

PROGRAM LTEOS(INPUT,OUTPUT,TAPE9=OUTPUT,TAPE10=INPUT) LTEOS
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0 21AP72
COMMON ECMAT(200),ETAMAT(200),A,B1,B2, C1,C2,C3,C5,C4,D1,AK, 21AP72
1 EREF,TREF,SAVE(50), P0,THETIN,RHOIN,PTOT,ETOT,RCOLD 21AP72
DIMENSION THETA(100),RHO(100) LTEOS

C EXPLA
C THIS SECTION OF THE CODE SETS UP THE MIXED PHASE REGION AND INPUTS EXPLA
C THE TEMPERATURE AND DENSITY FOR THE ISOTHERMS EXPLA
C EXPLA
C***** CALCULATES THE MIXED PHASE BOUNDARY **** * EXPLA
6 CALL CRTBND LTEOS
C***** CALCULATES DESIRED ISOTHERMS OR TEMPERATURE DENSITY POINTS ***** EXPLA
READ (10,1) NTHETA,NRHO LTEOS
1 FORMAT(2I4) LTEOS
IF(NTHETA) 11,6,4 LTEOS
4 READ(10,2)(THETA(I),I=1,NTHETA) LTEOS
READ (10,2) (RHO(I),I=1,NRHO) LTEOS
2 FORMAT(6E12. 5) LTEOS
DO 10 I = 1,NTHETA LTEOS
PRINT 3,THETA(I) LTEOS
3 FORMAT(1H1,2X,*TEMPERATURE = *,1PE12. 5//7X,*RHO*,7X,*PRESSURE*,5X, LTEOS
1 *ENERGY*)/ LTEOS
THETIN = THETA(I) LTEOS
DO 10 J = 1,NRHO LTEOS
RHOIN = RHO(J) LTEOS
CALL ISOCAL LTEOS
PRINT 5,RHOIN,PTOT,ETOT LTEOS
5 FORMAT(2X,1P10E12. 5) LTEOS
10 CONTINUE LTEOS
GO TO 6 LTEOS
11 STOP LTEOS
END LTEOS
SUBROUTINE CRTBND LTEOS
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0 21AP72
COMMON ECMAT(200),ETAMAT(200),A,B1,B2, C1,C2,C3,C5,C4,D1,AK, 21AP72
1 EREF,TREF,SAVE(50), P0,THETIN,RHOIN,PTOT,ETOT,RCOLD 21AP72
DIMENSION GEN(20),C(2,2),AP(2),RP(2),IROW(2),TEMP(2),TSTORE(100), LTEOS
1 ETA1(100),ETA2(100),PRESS1(100),PRESS2(100),ENERG1(100), LTEOS
2 ENRG2(100),PCHECK(50),GCHECK(50) LTEOS
DATA (GEN(I),I=1,14)/0., 5.1., .2., .4., .8., .16., .1., .05., .005., .0005., .00005 LTEOS
1 ,1., .2./ LTEOS
DIMENSION COLDP(12) 29AP72
DATA COLDP/. 9524., 96154., 97087., 98039., 990991., 1. 0000, 1. 0417, 1. 087, 29AP72
1 1. 1364, 1. 1905, 1. 250, 1. 66666/ 29AP72

C 29AP72
C MAIN SUBROUTINE - IT CALCULATES (IN THIS ORDER) THE T=0 CURVE, THE 29AP72
C CRITICAL POINT, THE MIXED PHASE REGION AND THE ISOTHERM PRESSURES 29AP72
C AND ENERGIES 29AP72

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```

C***** SETS UP T=0 CALCULATION **** -----
200 READ (10,1) ATMNO,ATMWWT,R0,S,C0,P0,U,H4 29AP72
1 FORMAT(8E10. 3) LTEOS
IF(ATMNO .GT. 25. . AND. ATMNO .LT. 27.) GO TO 990 LTEOS
IF(ATMWWT .EQ. 0) GO TO 1001 LTEOS
B = 125.*R0 LTEOS
CALL EOS(0,B,,01,PUPPER,EUPPER) LTEOS
PUPPER = PUPPER*PSI(125.,.01) 21AP72
CALL COLCOF(S,C0,PUPPER,U) LTEOS
PRINT 4,ATMNO,R0,ATMWWT,RCOLD,S,U,C0,P0,PUPPER,H4 4APR72
4 FORMAT(1H1,28X,*INPUT PARAMETERS*//* ATOMIC NUMBER = *,1PE12. 5, LTEOS
1 * NORMAL DENSITY(GM/CM3) = *,E12. 5,/* ATOMIC WEIGHT = *, LTEOS
2 E12. 5,* COLD DENSITY(GM/CM3) = *,E12. 5/* HUGONIOT S = * 4APR72
3 ,E12. 5,* COHESIVE ENERGY(EV) = *,E12. 5/* HUGONIOT C0 = LTEOS
4 *,E12. 5,* TENSILE STRENGTH(MBARS) = *,E12. 5 /32X,* PRESSURE(ET LTEOS
5 A=125)(MBARS)= *,E12. 5/32X,* DEBYE TEMPERATURE(EV) = *,E12. 5/) 4APR72
PRINT 8,GAMMA,D1,AK,C1,C2,C3,C4,C5,A,B1,B2 LTEOS
8 FORMAT(1H0,/- ----- EXPLA
6 /* 22X,*T = 0 ISOTHERM CALCULATIONS*//* GRUNEISEN GAMMA = *, EXPLA
1 1PE12. 5,/* MINIMUM PRESSURE LOCATION(ETA) = D1 = *,E12. 5//* EXPLA
2 EQUATION CONSTANTS*/* ETA LESS THAN D1----- K = *,E12. 5//* ETA EXPLA
3 BETWEEN D1 AND 1. - C1 = *,E12. 5/24X,*C2 = *,E12. 5/24X,*C3 = *,E12. 5 EXPLA
4 /24X,*C4 = *,E12. 5/24X,*C5 = *,E12. 5//* ETA GREATER THAN 1.----A EXPLA
5 = *,E12. 5/24X,*BR = *,E12. 5/24X,*BA = *,E12. 5) EXPLA
C***** START OF CRITICAL POINT SEARCH SECTION **** -----
T0 = .05 LTEOS
ESTART = AK*D1/(AK + 1.) + .11*D1 LTEOS
EREF = 0. LTEOS
TREF = 0. LTEOS
DELT = 1. LTEOS
ITEMP = 8 LTEOS
IRHO = 8 LTEOS
DELRHO = GEN(IRHO) LTEOS
3 S8 = 1. LTEOS
CALL PDPCAL(T0,ESTART,PRES,PRESP,S0,1) 29AP72
SREF = S0 LTEOS
IF(S8*SREF .GT. 0) GO TO 6 LTEOS
ESTART = 1. LTEOS
PRINT 5 LTEOS
5 FORMAT(1X,*AM RESTARTING ETA AT 1.*) LTEOS
GO TO 3 LTEOS
6 ESTART = ESTART*(1. - DELRHO) LTEOS
CALL PDPCAL(T0,ESTART,PRES,PRESP,S0,1) 29AP72
IF(S8*S0 .LT. 0) GO TO 10 LTEOS
SREF = S0 LTEOS
IF(ESTART .GT. .05) GO TO 6 LTEOS
PRINT 7,ESTART LTEOS
7 FORMAT(1X,*CAN NOT FIND NEG. SEC. DERIV. DOWN TO ETA = *,1PE12. 5) LTEOS
GO TO 1000 LTEOS
10 IF(ABS(S0) .LT. 1.E-5) GO TO 15 LTEOS
ESTART = ESTART*(1. + DELRHO*(1. - ABS(SREF/(SREF- S0)))) LTEOS
CALL PDPCAL(T0,ESTART,PRES,PRESP,S0,1) 29AP72
SREF = S0 LTEOS

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IF(ABS(SREF) . LT. 1. E-5) GO TO 15          LTEOS
S8 = ABS(SREF)/SREF                         LTEOS
DELRHO = S8*ABS(DELRHO/10.)                  LTEOS
IF(ABS(DELRHO) . GT. .000001) GO TO 6       LTEOS
PRINT 11,ESTART,PRES,S0                      LTEOS
11 FORMAT(1X,*CAN NOT CONVERGE ON ZERO SECOND DERV., ETA =*,1PE12.5,    LTEOS
      1 *PRESSURE =*,E12.5,* AND P SEC. DERV. =*,E12.5)                 LTEOS
      GO TO 1000                           LTEOS
15 IF(PRESP . LT. 0) GO TO 20                LTEOS
      PRINT 16,ESTART                         LTEOS
16 FORMAT(1X,*FIRST DERV. IS POS. AND SEC. DERV. IS NEG. ANT ETA =*,    LTEOS
      1 1PE12.5, * RESTART*)                   LTEOS
      IF(PRESP . LT. 1. E-4) GO TO 40           29AP72
      GO TO 1000                           LTEOS
20 IF(ABS(PRESP) . LT. 1. E-5) GO TO 40        LTEOS
      DO 25 I = 1,2                          LTEOS
      AI = I                                LTEOS
      E = ESTART*(1. + (AI - 1.5)*.001)       LTEOS
      B = E*R0                               LTEOS
      CALL EOS(0,B,.01,PLOWER,ELOWER)         LTEOS
25 SAVE(I) = PLOWER                         LTEOS
      CALL COLD(ESTART,PCOLD,PPCOLD,ECOLD,EPCOLD)   LTEOS
28 PPREF = PRESPE                         LTEOS
26 TSAVE = T0                            LTEOS
      T0 = T0 + DELT*T0                      LTEOS
      CALL PDPCAL(T0,ESTART,PRES,PRESP,S0,0)     29AP72
      IF(PRESP . GT. 0) GO TO 30             LTEOS
      IF(ABS(PRESP) . LT. 1. E-5) GO TO 35       LTEOS
      IF(T0 . LT. 10.) GO TO 28              LTEOS
      PRINT 27,T0,ESTART                     LTEOS
27 FORMAT(1X,*TEMP. IS TOO LARGE,START AGAIN. T0 = *,1PE12.5,* ETA =*    LTEOS
      1 ,E12.5)                            LTEOS
      GO TO 1000                           LTEOS
30 T0 = TSAVE + (T0 - TSAVE)*ABS(PPREF/(PPREF-PRESP))*.95      LTEOS
      CALL PDPCAL(T0,ESTART,PRES,PRESP,S0,0)     29AP72
      IF(PRESP . GT. 0) GO TO 30             LTEOS
      IF(ABS(PRESP) . LT. 1. E-5) GO TO 35       LTEOS
      DELT = .01*DELT                      LTEOS
      IF(DELT . GT. .000001) GO TO 26         LTEOS
      PRINT 31,T0,PRESPE                    LTEOS
31 FORMAT(1X,*CAN NOT CONVERGE ON LOCATION OF ZERO SLOPE*,1PE12.5)    LTEOS
      GO TO 1000                           LTEOS
35 DELT = GEN(ITEMP)                      LTEOS
      ITEMPE = ITEMPE + 1                  LTEOS
      CALL PDPCAL(T0,ESTART,PRES,PRESP,S0,1)     29AP72
      IF(ABS(S0) . LT. 1. E-5) GO TO 40       LTEOS
      SREF = S0                            LTEOS
      S8 = ABS(SREF)/SREF                  LTEOS
      DELRHO = S8*GEN(IRHO)                LTEOS
      IRHO = IRHO + 1                     LTEOS
      GO TO 6                            LTEOS
40 CALL PGCAL(0,ESTART,T0,PCRIT,PPTOT,ECRIT,GTOT,GPTOT)      21AP72
      PRINT 41,T0,PCRIT,ESTART            21AP72

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41 FORMAT(1H0,/*----- EXPLA
1 *22X,*CRITICAL POINT RESULTS*//* T-CRIT(EV) = *,1PE15.7/* P- EXPLA
2 CRIT(MBARS) = *,E15.7/* ETA-CRIT = *,E15.7) EXPLA
TCRIT = T0 LTEOS
ETACRT = ESTART LTEOS
C LTEOS
C***** START OF MIXED PHASE BOUNDARY CALCULATION ***** LTEOS
C LTEOS
ETA1(1) = ETACRT LTEOS
ETA2(1) = ETACRT LTEOS
PRESS1(1) = PCRIT LTEOS
PRESS2(1) = PCRIT LTEOS
ENERG1(1) = ECRIT LTEOS
ENERG2(1) = ECRIT LTEOS
TSTORE(1) = TCRIT LTEOS
ITEMP = 2 LTEOS
PRINT 42 LTEOS
42 FORMAT(1H1,1X,*MIXED PHASE BOUNDARY PARAMATERS*//3X,*TEMPERATURE*, EXPLA
1 8X,*ETA*,9X,*PRESSURE*,7X,*ENERGY*,5X,*GIBBS ENERGY*/7X,*EV)*,24X EXPLA
2 ,(MBAR)*,5X,(MBAR-CC/GM)*//) EXPLA
ICYCLE = 1 LTEOS
DELTP = .05 LTEOS
DELT = .1 LTEOS
IF(T0 . LE. 1.) DELT = .05 29AP72
MTEMP = 10.*T0 LTEOS
TEM = MTEMP LTEOS
T0 = TEM/10. LTEOS
IF(TCRIT - T0 . LT. DELT) T0 = T0 - DELT LTEOS
E = ESTART - .15 LTEOS
IF(E . LT. 0.) E = .01 LTEOS
CALL PGCAL(0,E,T0,PTO,PPTOT,ETOT,GTOT,GPTOT) 4APR72
DO 45 I = 1,100 LTEOS
E = E + .01 LTEOS
CALL PGCAL(0,E,T0,PNEW,PPTOT,ETOT,GTOT,GPTOT) 4APR72
IF (PNEW . GT. PTO ) GO TO 45 LTEOS
SAVE(1) = E - .06 LTEOS
ELOW = E + .01 18APR72
GO TO 46 LTEOS
45 PTO = PNEW LTEOS
PRINT 43 LTEOS
43 FORMAT(* FAILED TO FIND STARTING POINT FOR CRITICAL BOUNDARY*) LTEOS
46 PTO = PNEW LTEOS
DO 48 I = 1,100 LTEOS
E = E + .01 LTEOS
CALL PGCAL(0,E,T0,PNEW,PPTOT,ETOT,GTOT,GPTOT) 4APR72
IF(PNEW . LT. PTO ) GO TO 48 LTEOS
SAVE(2) = E + .03 LTEOS
EHIGH = E - .01 18APR72
GO TO 50 LTEOS
48 PTO = PNEW LTEOS
50 CONTINUE LTEOS
DO 60 I = 1,50 LTEOS
S8 = 1. LTEOS
DO 55 J = 1,2 LTEOS

```

```

E = SAVE(J) LTEOS
CALL PGCAL(1,E,T0,PTOT,PPTOT,ETOT,GTOT,GPTOT) 20APR72
C(2,J) = S8*PPTOT LTEOS
I1 = 8 + 2*J LTEOS
SAVE(I1) = PTOT LTEOS
C(1,J) = S8*GPTOT 20APR72
I3 = 20 + 2*J LTEOS
I2 = I1 + 1 LTEOS
SAVE(I3) = ETOT LTEOS
SAVE(I2) = GTOT 20APR72
55 S8 = -1. LTEOS
GCHECK(I) = SAVE(11) LTEOS
PCHECK(I) = SAVE(12) LTEOS
AP(1) = SAVE(13) - SAVE(11) LTEOS
AP(2) = SAVE(12) - SAVE(10) LTEOS
IF(ABS(AP(1)/SAVE(11)) . LT. 1.E-6) GO TO 57 LTEOS
56 IF(I . LE. 3) GO TO 75 LTEOS
IF(ABS((GCHECK(I) - GCHECK(I-2))/GCHECK(I)) . GT. 1.E-10) GO TO 75 LTEOS
IF(ICYCLE . GT. 1) GO TO 81 LTEOS
ICYCLE = 2 LTEOS
TCYCLE = T0 LTEOS
T0 = T0 + .005 LTEOS
GO TO 50 LTEOS
57 IF(ABS(AP(2)/SAVE(10)) . LT. 1.E-5) GO TO 105 LTEOS
IF(I . LT. 3) GO TO 75 LTEOS
IF(ABS((PCHECK(I)- PCHECK(I-2))/PCHECK(I)) . LT. 1.E-10) GO TO 64 LTEOS
75 CONTINUE LTEOS
CALL MATINV(C,2,2,IROW,TEMP) LTEOS
CALL MATMPY(2,2,1,C,2,AP,2,RP,2) LTEOS
SAVE(1) = SAVE(1) + RP(1) 4APR72
SAVE(2) = SAVE(2) + RP(2) 4APR72
85 IF(SAVE(1) . GT. ETACRT) GO TO 95 LTEOS
IF(SAVE(2) . LT. ETACRT) GO TO 95 LTEOS
IF(SAVE(1) . LT. 0) SAVE(1) = (SAVE(1) - RP(1))/2. LTEOS
IF(SAVE(1) . GT. ELOW) SAVE(1) = ELOW - .01 18APR72
IF(SAVE(2) . LT. EHIGH) SAVE(2) = EHIGH + .01 18APR72
60 CONTINUE LTEOS
IF(ABS(AP(1)/SAVE(11)) . GT. 1.E-6) GO TO 89 LTEOS
64 IF(SAVE(10) . GT. 1.E-8) GO TO 89 LTEOS
IPOS = 0 LTEOS
IF(SAVE(10) . LT. SAVE(12)) IPOS = 1 LTEOS
SIG = ABS(SAVE(10) - SAVE(12))/(SAVE(10) - SAVE(12)) LTEOS
STEP = 1.E-7 LTEOS
74 ITEM = 1 LTEOS
DO 76 I4 = 1,11 LTEOS
AI4 = I4 LTEOS
ETE = SAVE(2)*(1. + SIG*STEP*AI4) LTEOS
CALL PGCAL(1,ETE,T0,PTEMP,PPTOT,ETOT,GTEM,GPTOT) 4APR72
IPOSP = 0 LTEOS
IF(SAVE(10) . LT. PTEMP) IPOSP = 1 LTEOS
IF(IPOS . NE. IPOSP) GO TO 62 LTEOS
ITEM = ITEM + 1 LTEOS
76 CONTINUE LTEOS

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PRINT 78,T0,ETE,PTEMP,ETOT,GTEM	EXPLA
78 FORMAT(1X,*CAN NOT FIND CROSS POINT*,1P6E15. 7)	LTEOS
GO TO 150	LTEOS
62 IF(ITEM . GT. 1) GO TO 77	LTEOS
STEP = STEP/10.	LTEOS
IF(STEP . GT. 1.E-14) GO TO 74	4APR72
IF(SIG . LT. 0) ETE = SAVE(2)	4APR72
77 IF(ABS((GTEM - SAVE(13))/SAVE(13)) . GT. 1.E-5) GO TO 69	4APR72
SAVE(12) = SAVE(10)	LTEOS
65 DO 82 I4 = 1,200	4APR72
AI4 = I4	LTEOS
ETE1 = ETE*(1. + STEP*AI4)	LTEOS
SAVE(2) = ETE1*(1. - STEP)	LTEOS
CALL PGCAL(1,ETE1,T0,PTEMP,PPTOT,ETOT,GTEM,GPTOT)	20APR72
IF(ABS((GTEM - SAVE(13))/SAVE(13)) . LT. 1.E-8) GO TO 105	LTEOS
82 CONTINUE	LTEOS
GO TO 105	LTEOS
69 PRINT 70	LTEOS
70 FORMAT(1X,*NUMERIC PROBLEMS PREVENT CONVERGENCE*)	LTEOS
GO TO 65	LTEOS
81 PRINT 70	LTEOS
GO TO 111	LTEOS
89 PRINT 90	LTEOS
90 FORMAT(1X,*CAN NOT CONVERGE IN 50 TRIES*)	LTEOS
IF(ICYCLE . GT. 1) GO TO 150	29AP72
ICYCLE = 2	29AP72
TCYCLE = T0	29AP72
T0 = T0 + .01	29AP72
GO TO 50	29AP72
95 PRINT 100,SAVE(1),ETACRT,SAVE(2)	LTEOS
100 FORMAT(1X,*ETAS ARE CROSSING CRITICAL ETA*,1P3E12. 5)	LTEOS
GO TO 150	4APR72
105 TSTORE(ITEMP) = T0	LTEOS
ETA1(ITEMP) = SAVE(1)	LTEOS
ETA2(ITEMP) = SAVE(2)	LTEOS
PRESS1(ITEMP) = SAVE(10)	LTEOS
PRESS2(ITEMP) = SAVE(12)	LTEOS
ENERG1(ITEMP) = SAVE(22)	LTEOS
ENERG2(ITEMP) = SAVE(24)	LTEOS
PRINT 110,T0,ETA1(ITEMP),PRESS1(ITEMP),ENERG1(ITEMP),SAVE(11),	LTEOS
1 ETA2(ITEMP),PRESS2(ITEMP),ENERG2(ITEMP),SAVE(13)	LTEOS
110 FORMAT(2X,5(1PE12. 5,2X)/16X,4(E12. 5,2X)/)	LTEOS
ITEMP = ITEMP + 1	LTEOS
111 IF(ICYCLE . GT. 1) T0 = TCYCLE	4APR72
ICYCLE = 1	4APR72
112 IF(T0 . LT. .11) DELTP = .025	LTEOS
T0 = T0 - DELTP	LTEOS
IF(T0 . LT. .049) GO TO 150	4APR72
EFAC = 2.	LTEOS
IF(T0 . LT. .2) EFAC = 1.	LTEOS
SAVE(1) = SAVE(1)/EXP(TCRIT/(EFAC*T0))	LTEOS
SAVE(2) = ETA2(ITEMP-1)*1.20	LTEOS
IF(ITEMP . GT. 6) SAVE(2) = 2.*ETA2(ITEMP-1) - ETA2(ITEMP-2)	LTEOS

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IF(SAVE(2) . GT. 1.) SAVE(2) = .99          LTEOS
GO TO 50                                     LTEOS
C                                           LTEOS
150  NBOUND = ITEMP - 1                      LTEOS
      PTO = PRESS1(NBOUND)                   4APR72
      E = ETA2(NBOUND)                     4APR72
      DO 155 I = 1,100                      4APR72
      E = E - .01                          4APR72
      CALL PGCAL(0,E,TSTORE(NBOUND),PTOT,PPTOT,ETOT,GTOT,GPTOT) 4APR72
      IF(PTOT . GT. PTO) GO TO 156          4APR72
155  PTO = PTOT                           4APR72
156  EBOUND = E + .01                      4APR72
      GO TO 160                           LTEOS
990  PRINT 991                           LTEOS
991  FORMAT(* IRON IS NOT AVAILABLE AT PRESENT TIME*) EXPLA
160  RETURN                                LTEOS
C***** ISOTHERM CALCULATION *****
C***** ISOCAL
ENTRY ISOCAL                         EXPLA
E = RHOIN/R0                          LTEOS
IF(THETIN . LT. .01) THETIN = .01      4APR72
IF(THETIN . GT. TCRIT) GO TO 240     LTEOS
DO 205 IJ = 1,NBOUND                  LTEOS
IF(THETIN . GE. TSTORE(IJ)) GO TO 207 LTEOS
205  CONTINUE                            LTEOS
IF(E . GT. EBOUND) GO TO 240          4APR72
PTOT = 0.                             4APR72
ETOT = 0.                             4APR72
GO TO 1001                           4APR72
207  TINTER = (TSTORE(IJ)- THETIN)/(TSTORE(IJ)- TSTORE(IJ- 1)) LTEOS
      ETAHI = ETA2(IJ) - TINTER*(ETA2(IJ) - ETA2(IJ- 1)) LTEOS
      ETALO = ETA1(IJ) - TINTER*(ETA1(IJ) - ETA1(IJ- 1)) LTEOS
      IF(E . GT. ETAHI) GO TO 240          LTEOS
      IF(E . LT. ETALO) GO TO 240          LTEOS
      PTOT = PRESS1(IJ) - TINTER*(PRESS1(IJ) - PRESS1(IJ- 1)) LTEOS
      ENGHI = ENERG2(IJ) - TINTER*(ENERG2(IJ) - ENERG2(IJ- 1)) LTEOS
      ENGLO = ENERG1(IJ) - TINTER*(ENERG1(IJ) - ENERG1(IJ- 1)) LTEOS
      ETOT = ENGHI - (ENGHI- ENGLO)*(ETAHI - E)/(ETAHI - ETALO) LTEOS
      GO TO 1001                           LTEOS
240  CALL PGCAL(0,E,THETIN,PTOT,PPTOT,ETOT,GTOT,GPTOT) 29AP72
      GO TO 1001                           LTEOS
1000 PRINT 1002                         LTEOS
1002 FORMAT(1X,*CAN NOT WORK THIS CASE*) LTEOS
1001 RETURN                               LTEOS
END                                     LTEOS
SUBROUTINE EOS(I5,DENSITY,TEMPTUR,P2,U) LTEOS
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1  N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0           21AP72
DATA Q/0. ,5.1. ,2. ,4. ,8. ,16. ,1. E+ 200/ LTEOS
DATA Q3/0. ,125.1. ,8. ,64. ,512. ,4096. / LTEOS
C                                           EXPLA
C   ELECTRONIC EQUATION OF STATE MAIN SUBROUTINE - FIND PRESSURE, EXPLA
C   INTERNAL ENERGY AND ELECTRONIC GIBBS FREE ENERGY FOR SPECIFIC EXPLA

```

C	TEMPERATURE AND DENSITY	EXPLA
C		EXPLA
	Z=ATMNO	LTEOS
	A=ATMWWT	LTEOS
	TO=TEMPTUR	LTEOS
	RO=DENSITY	LTEOS
	KKK=0	LTEOS
	Z9=Z**. 3333333	LTEOS
	Z11=1. /Z9	LTEOS
	R=(2. 67404715*A/RO)**. 3333333	LTEOS
	Z10=R*Z9	LTEOS
	RQB=R**3	LTEOS
15	CONTINUE	LTEOS
	TO32=SQRT(TO)*TO	LTEOS
	TO1=1. /TO	LTEOS
	AO=. 6057*Z9	LTEOS
	DO 1 I=2,8	LTEOS
	IF (Z10. LT. Q(I)) GO TO 2	LTEOS
1	CONTINUE	LTEOS
2	J1=I	LTEOS
	N=I- 1	LTEOS
	QN=Q(N)	LTEOS
	QN3=QN**3	LTEOS
	ITRAN=1	LTEOS
	IF (Z10. LT. 16.) ITRAN=2	LTEOS
	R2=R	LTEOS
	FNZR2=1. /(1. + AO*R2)	LTEOS
	FNZR2=FNZR2**2*(2. *AO*R2*FNZR2+1.)*Z	LTEOS
	F1=236. 34647*FNZR2/(RQB*TO32)	LTEOS
	CALL SUB400	LTEOS
	E3=E4	LTEOS
	CALL SUB1100	LTEOS
	Z2=S2	LTEOS
	R2=R2*. 99	LTEOS
	FNZR2=1. /(1. + AO*R2)	LTEOS
	FNZR2=FNZR2**2*(2. *AO*R2*FNZR2+1.)*Z	LTEOS
	F1=236. 34647*FNZR2/(RQB*TO32)	LTEOS
	CALL SUB400	LTEOS
	E3=E4	LTEOS
	CALL SUB1100	LTEOS
	Z3=S2	LTEOS
	IF (Z2/Z. GE. 1.) GO TO 3	LTEOS
	ISW=1	LTEOS
	R2=. 1	LTEOS
	Z2=Z	LTEOS
	GO TO 4	LTEOS
3	ISW=2	LTEOS
	R2=R/3.	LTEOS
	IF (Z2/Z3. LT. 1.) GO TO 8	LTEOS
4	R3=R2	LTEOS
	FNZR2=1. /(1. + AO*R2)	LTEOS
	FNZR2=FNZR2**2*(2. *AO*R2*FNZR2+1.)*Z	LTEOS
	F1=236. 34647*FNZR2/(RQB*TO32)	LTEOS

	CALL SUB400	LTEOS
	E3=E4	LTEOS
	CALL SUB1100	LTEOS
	Z4=Z2- S2	LTEOS
	IF (ABS(Z4/Z2). LT. 1. E- 10) GO TO 5	LTEOS
	R2=R3*. 99	LTEOS
	FNZR2=1. /(1. + AO*R2)	LTEOS
	FNZR2=FNZR2**2*(2. *AO*R2*FNZR2+ 1.)*Z	LTEOS
	F1=236. 34647*FNZR2/(RQB*TO32)	LTEOS
	CALL SUB400	LTEOS
	E3=E4	LTEOS
	CALL SUB1100	LTEOS
	Z3=Z2- S2	LTEOS
	R2=R3- . 01*R3*Z4/(Z4- Z3)	LTEOS
	GO TO 4	LTEOS
5	GO TO (9,6), ISW	LTEOS
6	PRINT 10	LTEOS
	PRINT 11	LTEOS
7	X=E3	LTEOS
	CALL SUB600	LTEOS
	CALL SUB1100	LTEOS
	Z4=Z- S2	LTEOS
	IF (ABS(Z4/Z). LT. 1. E- 10) GO TO 9	LTEOS
	E3=. 99*E3	LTEOS
	X=E3	LTEOS
	CALL SUB600	LTEOS
	CALL SUB1100	LTEOS
	Z3=Z- S2	LTEOS
	E3=(1. 010101- . 01010101*Z4/(Z4- Z3))*E3	LTEOS
	GO TO 7	LTEOS
8	PRINT 12	LTEOS
	PRINT 13	LTEOS
	STOP 276	LTEOS
9	X=E4	LTEOS
	CALL SUB600	LTEOS
	CALL SUB800	LTEOS
	ETE = RO/R0	21AP72
	PS = PSI(ETE,TEMPTUR)	21AP72
	IF(I5 . EQ. 0) PS = 1.	21AP72
	PO=FNZR2*TO/RQB*Y5/Y*1. 722*PS	21AP72
	IF (KKK. GT. 0) GO TO 20	LTEOS
	P1=PO	LTEOS
20	CONTINUE	LTEOS
	R5=AO*R2	LTEOS
	R6=AO*R	LTEOS
	R7=R2/R	LTEOS
	R8=1. + R5	LTEOS
	Z5=FNZR2/Z	LTEOS
	B1=ALOG(R8)	LTEOS
	V1=(Z5/R6**2)*(1. /R8+ B1- 1.)	LTEOS
	V2=Z5**2*R7**3*(R7**2*. 1- A1*. 333333)	LTEOS
	V3=- . 4*R6/R8**5	LTEOS
	V4=Z5/R6**2	LTEOS

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V4=V4*((- 3. *R5**3+ 9. *R5**2+ 18. *R5+ 8.)/(6. *R8**3)- 4. /3. + B1) LTEOS
V5=(- A1*Z5*2.)*(1. - (1. + 3. *R5)/R8**3)/6.) LTEOS
V6=(Z5/2. )*R7**2+(2. *R6/3. )*(- 1. /R8**3) LTEOS
V7=(Z5*. 5)*(1. - R7**2) LTEOS
V8=. 1- R7**2*(. 5- . 5*R7+. 1*R7**3) LTEOS
VO=- Z**2*(V1+ V2+ V3+ V4+ V5+ V6+ V7)- FNZR2**2*V8 LTEOS
UO=(39. 383*VO)/(R*A)**PS 21AP72
IF(KKK, GT, 0) GO TO 30 LTEOS
U1= 1. 5*(P1/RO)+ UO*. 5 LTEOS
IF(I5 . EQ. 1) GO TO 25 LTEOS
P2 = P1 LTEOS
U = U1 LTEOS
GO TO 35 LTEOS
25 TO = . 01 LTEOS
KKK=1 LTEOS
GO TO 15 LTEOS
30 U=1. 5*(PO/RO)+ UO*. 5 LTEOS
P2=P1- PO LTEOS
U=U1- U LTEOS
35 RETURN 21AP72
C LTEOS
10 FORMAT (* LOW TEMP. LOW DENSITY- ACCURACY*) LTEOS
11 FORMAT (* DISCONTINUOUS POTENTIAL POSSIBLE*) LTEOS
12 FORMAT (* NO UNIQUE SOL. CAN BE FOUND*) LTEOS
13 FORMAT (* SEE LINE 214*) LTEOS
END LTEOS
FUNCTION FNI (S) LTEOS
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0 21AP72
C EXPLA
C CALCULATES INNER JOIN RADIUS OF ELECTRONIC POTENTIAL EXPLA
C EXPLA
X1 = S/R EXPLA
A1=(Z/FNZR2)*(R/R2/(1. + AO*R2)**2)- R/R2+ 1. 5 LTEOS
FNI=27. 2*Z/R LTEOS
FNI=FNI*(1. /X1)*(1. /(1. + AO*R*X1)**2) LTEOS
FNI=FNI+ 27. 2*FNZR2*(X1**2/2. - A1)/R LTEOS
RETURN LTEOS
END LTEOS
SUBROUTINE SUB600 LTEOS
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0 21AP72
C EXPLA
C CALCULATES THE FERMI DIRAC INTEGRAL OF ORDER 1/2 EXPLA
C EXPLA
IF(X . LE. 4.) GO TO 2 EXPLA
Y=. 666667*SQRT(X)*X LTEOS
Y1=(1. + 1. 2337/X**2+ 1. 06541/X**4) LTEOS
IF (X. GT. 1. E+ 6) GO TO 1 LTEOS
Y1=Y1+ 9. 70152/X**6 LTEOS
1 Y=Y*Y1 LTEOS

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      RETURN                                     LTEOS
2     IF (X. GE. - 2.) GO TO 3                 LTEOS
      W1=EXP(X)                                LTEOS
      W2=W1**W1                                LTEOS
      Y=W1*(. 886227-. 2852038*W1+. 17055438*W2) LTEOS
      RETURN                                     LTEOS
3     T=(X+ 2. )/6.                           LTEOS
      Q1=3. 09954*T                            LTEOS
      Y=. 115137+ 5. 66425*T                  LTEOS
      Y=Y+ (T- 1. )*T*(6. 46229- 1. 4536*EXP(- Q1)) LTEOS
      RETURN                                     LTEOS
      END                                         LTEOS
      FUNCTION FNO (S)                         LTEOS
      COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1     N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
      COMMON ATMWT,ATMNO,H4,GAMMA,R0           21AP72
C
C   CALCULATES OUTER IONIC RADIUS OF ELECTRONIC POTENTIAL EXPLA
C
C   X1 = S/R                                 EXPLA
      FNO=(27. 2*FNZR2/R)*(1. /X1+ X1**2/2. - 1. 5) EXPLA
      RETURN                                     LTEOS
      END                                         LTEOS
      SUBROUTINE SUB800                          LTEOS
      COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1     N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
      COMMON ATMWT,ATMNO,H4,GAMMA,R0           21AP72
C
C   CALCULATES THE FERMI DIRAC INTEGRAL OF ORDER 3/2 EXPLA
C
C   IF(X . LT. 4.) GO TO 1                   EXPLA
      Y5=SQRT(X)*(4*X**2+ 2. 467401-. 7102746/X**2) LTEOS
      Y5=Y5- SQRT(X)*2. 771862/X**4               LTEOS
      RETURN                                     LTEOS
1     IF (X. GT. - 2.) GO TO 2                 LTEOS
      X5=EXP(X)                                LTEOS
      X6=X5*X5                                LTEOS
      Y5=1. 32934*X5                            LTEOS
      Y5=Y5*(1. -. 176777*X5+. 06415*X6)       LTEOS
      RETURN                                     LTEOS
2     T=(X+ 2. )*. 166667                     LTEOS
      Q1=3. 09954*T                            LTEOS
      Y5=. 115137*T+ 5. 66425/2. *T**2          LTEOS
      Y6=EXP(- Q1)                                LTEOS
      Y7=6. 46229*T**2*(T*. 333333-. 5)+ Y5    LTEOS
      Y5=(2. - Y6*(Q1**2+ 2. *Q1+ 2. ))*. 03358213 LTEOS
      Y5=Y5-(1. - Y6*(Q1+ 1. ))*. 10408916      LTEOS
      Y5=- 1. 4536*Y5                            LTEOS
      Y5=((Y5+ Y7)*6. + . 11720928)            LTEOS
      Y5=Y5*1. 5                                LTEOS
      RETURN                                     LTEOS
      END                                         LTEOS
      SUBROUTINE SUB1100                         LTEOS

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COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q      COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2                          COM1
    COMMON ATMWT,ATMNO,H4,GAMMA,R0                                     21AP72
C
C THIS SUBROUTINE DOES THE INTEGRATION OF THE ELECTRONIC POTENTIAL     EXPLA
C USING QUADRATURE FORMULAS                                         EXPLA
C                                         EXPLA
C                                         EXPLA
S1 = 0.                                              EXPLA
IF (N. LT. 2) GO TO 4                                     LTEOS
DO 3 J=2,N                                               LTEOS
S=Q(J)/Z9                                              LTEOS
IF (. 73*S/R2. GT. 1.) GO TO 1                           LTEOS
X=FNI(. 73*S)*TO1+ E3                                 LTEOS
GO TO 2                                              LTEOS
1 X=FNO(. 73*S)*TO1+ E3                               LTEOS
2 CALL SUB600                                         LTEOS
S1=S1+ Y*(Q3(J)- Q3(J- 1))/Z                         LTEOS
3 CONTINUE                                         LTEOS
4 CONTINUE                                         EXPLA
    GO TO (5,10), ITRAN                                LTEOS
5 CONTINUE                                         LTEOS
C R 16 (LOW DENSITY CASE)                                LTEOS
S=(16. + . 46*(Z10-16. )*. 5)*Z11                  LTEOS
S9=(16. + (Z10-16. )*. 5)*Z11                      LTEOS
IF (S/R2. LT. 1.) GO TO 6                           LTEOS
X=FNO(S)*TO1+ E3                                 LTEOS
CALL SUB600                                         LTEOS
GO TO 7                                              LTEOS
6 X=FNI(S)*TO1+ E3                               LTEOS
CALL SUB600                                         LTEOS
7 S1=S1+ Y*(S9**3- Q3(N)/Z)                         LTEOS
S=(S9+. 46*(R-16. *Z11)**. 5)                      LTEOS
IF (S/R2. LT. 1.) GO TO 8                           LTEOS
X=FNO(S)*TO1+ E3                                 LTEOS
CALL SUB600                                         LTEOS
GO TO 9                                              LTEOS
8 X=FNI(S)*TO1+ E3                               LTEOS
CALL SUB600                                         LTEOS
9 S1=S1+ Y*(RQB- S9**3)                            LTEOS
GO TO 14                                         LTEOS
10 IF (J1. LT. 3) GO TO 15                         LTEOS
S=(Q(N)+(Z10-Q(N))* . 46)*Z11                    LTEOS
11 IF (S/R2. LT. 1.) GO TO 12                         LTEOS
X=FNO(S)*TO1+ E3                                 LTEOS
CALL SUB600                                         LTEOS
GO TO 13                                         LTEOS
12 X=FNI(S)*TO1+ E3                               LTEOS
CALL SUB600                                         LTEOS
13 S1=S1+ Y*(RQB- Q3(N)/Z)                         LTEOS
14 S1=S1/3.                                         LTEOS
S2=S1*1. 2693229E- 2*TO32                         LTEOS
RETURN                                         LTEOS
15 S=. 73*R                                         LTEOS

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GO TO 11                                     LTEOS
END                                         LTEOS
SUBROUTINE SUB400                           LTEOS
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0               21AP72

C
C FINDS ETA GIVEN THE FERMI DIRAC INTEGRAL OF ORDER 1/2 FROM AN EXPLA
C APPROXIMATION FORMULA EXPLA
C EXPLA
C IF(F1 . LT. 5.77939) GO TO 3 EXPLA
E4=1.5**F1**.666667 LTEOS
1 X=E4 LTEOS
CALL SUB600 LTEOS
F2=F1-Y LTEOS
IF (ABS(F2/F1). LT. 1. E-10) GO TO 2 LTEOS
F3=1.-.4112335/X**2-1.7756865/X**4 LTEOS
F3=F3-.29.1045555/X**6 LTEOS
F3=-F3*SQRT(X) LTEOS
E4=E4-F2/F3 LTEOS
GO TO 1 LTEOS
2 E4=X LTEOS
RETURN LTEOS
3 IF (F1.GT..115137) GO TO 6 LTEOS
E4=1.128379186*F1 LTEOS
4 E5=E4*E4 LTEOS
E2=.886226925*E4*(1.-.321818*E4+.19245*E5) LTEOS
F2=F1-E2 LTEOS
IF (ABS(F2/F1). LT. 1. E-10) GO TO 5 LTEOS
F3=-.886226925*(1.-.643636*E4+.57735*E5) LTEOS
E4=E4-F2/F3 LTEOS
GO TO 4 LTEOS
5 E4=ALOG(E4) LTEOS
RETURN LTEOS
6 T=.9999 LTEOS
7 X=6.*T-2. LTEOS
CALL SUB600 LTEOS
F2=Y LTEOS
F2=F1-F2 LTEOS
IF (ABS(F2/F1). LT. 1. E-10) GO TO 8 LTEOS
W=EXP(-3.09954*T) LTEOS
F3=5.66425+T*(T-1.)*1.4536*3.09954*W LTEOS
F3=-F3-(2.*T-1.)*(6.46229-1.4536*W) LTEOS
T=T-F2/F3 LTEOS
GO TO 7 LTEOS
8 E4=6.*T-2. LTEOS
RETURN LTEOS
END LTEOS
FUNCTION PSI(E,T0) 21AP72
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2 COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0               21AP72

C

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C      CALCULATES THE MODIFICATION FUNCTION FOR THE ELECTRONIC PRESSURE,      21AP72
C      ETC. TO COMPENSATE FOR THERMAL EFFECTS AND MODEL PROBLEMS      21AP72
C      C      IF(E . LT. 1.) GO TO 1      21AP72
C      DEBYE = H4*EXP((GAMMA/E - (3. *E-1.)/(3. *E**2))*(E-1.))*E**. 6666667      21AP72
C      GO TO 10      21AP72
1     IF(E . GT. 1.E-10) GO TO 5      21AP72
T = H4*EXP(1.5 - 2. *GAMMA)      21AP72
SI = .018596*(R0/ATMWWT)**(2./3.)*T0*T/(ATMWWT*E**4./3.)      21AP72
GO TO 15      21AP72
5    DEBYE = H4*E*EXP(((3. *GAMMA-2. )+ .5*(1.-2. *GAMMA)*(E+1.))*(E-1.))      21AP72
10   SI = .018596*(T0/DEBYE**2)*(E*R0/ATMWWT)**. 6666667/ATMWWT      21AP72
15   EXT = (10. - 10. /(1. + SI))/T0      21AP72
IF(EXT . LT. 700.) GO TO 20      21AP72
PSI = 0.      21AP72
GO TO 25      21AP72
20  PSI = 2. /(1. + EXP(EXT))      21AP72
25  RETURN      21AP72
END      21AP72
SUBROUTINE COLD(ESAVE,PCOLD,PPCOLD,ECOLD,EPCOLD)      4APR72
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q      COM1
1    N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2      COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0      21AP72
COMMON ECMAT(200),ETAMAT(200),A,B1,B2,      C1,C2,C3,C5,C4,D1,AK,      21AP72
1    EREF,TREF,SAVE(50),      P0,THEtin,RHOIN,PTOT,ETOT,RCOLD      21AP72
C      FOR A SPECIFIC TEMPERATURE AND DENSITY, THE SUBROUTINE FINDS THE      EXPLA
C      T=0 PRESSURE AND INTERNAL ENERGY      EXPLA
C      EXPLA
C      EXPLA
C      TH = 1./3.      EXPLA
C      TI = 2./3.      LTEOS
C      E = R0*ESAVE/RCOLD      4APR72
C      IF(E . LT. 1.) GO TO 5      LTEOS
C      E1 = 1. - 1./E**TH      LTEOS
C      E2 = EXP(E1*B1)      LTEOS
C      E3 = EXP(E1*B2)      LTEOS
C      PCOLD = A*(E**TI*E2 - E**TI*E3)      LTEOS
C      G1 = E2*(5.*E**TI/3. + B1*E**TH/3.)      LTEOS
C      G2 = E3*(2. /(3.*E**TH) + B2/(3.*E**TI))      LTEOS
C      PPCOLD = A*(G1 - G2)      LTEOS
C      G3 = (E**TI - B1*E**TH)*E2-B1**2*EXP(B1)*(EPIN(B1)- EPIN(B1/E**TH))      LTEOS
C      G4 = G3 + B1 - 1. + 2./B2*(1. - E3)      LTEOS
C      ECOLD = 1.5*A*G4/R0      LTEOS
C      GO TO 21      LTEOS
5    IF(E . LT. D1) GO TO 10      LTEOS
C      E1 = 1. - E**TH      LTEOS
C      E2 = E**TH - D1**TH      LTEOS
C      E3 = 5.*E**TI - 4.*E**TH      LTEOS
C      G3 = C2 + E2*(C3 - E1*(C4 - C5*E1))      LTEOS
C      PCOLD = -E**TH*E1*(C1 + E2*G3)      LTEOS
C      G5 = -4.*E**TH*E1**3*E2**2+3.*E**TI*E1**2*E2**2-2.*E**TI*E1**3*E2      LTEOS
C      G4 = 4.*E**TH*E1**2*E2**2-2.*E**TI*E1*E2**2+2.*E**TI*E1**2*E2      LTEOS
C      G3 = E3*E2**2 - 2.*E**TI*E1*E2      LTEOS

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G2 = E3*E2 - E**TI*E1          LTEOS
PPCOLD = (C1*E3 + C2*G2 + C3*G3 + C4*G4 + C5*G5)/3.    LTEOS
GO TO 20                         LTEOS
10 PCOLD = P0*(AK+ 2. - (AK+ 1.)*E/D1)*(E/D1)**(AK+ 1.)    LTEOS
PPCOLD = P0*(AK+ 1.)*(AK+ 2.)/D1*((E/D1)**AK - (E/D1)**(AK+ 1.))    LTEOS
20 ECOLD = 0.                      LTEOS
21 CONTINUE                       LTEOS
IF(E .GT. 1.) GO TO 50           LTEOS
IF(E .LT. D1) GO TO 40           LTEOS
IF(E .GT. ETAMAT(1)) GO TO 30   LTEOS
DO 25 I = 2,200                  LTEOS
IF(E .GT. ETAMAT(I)) GO TO 35   LTEOS
25 CONTINUE                       LTEOS
30 ECOLD = ECMAT(1)*(E - ETAMAT(1))/(1. - ETAMAT(1))/R0    LTEOS
GO TO 50                         LTEOS
35 ECOLD = (ECMAT(I) + (E - ETAMAT(I))*(ECMAT(I) - ECMAT(I- 1))/    LTEOS
1 (ETAMAT(I- 1) - ETAMAT(I)))/R0    LTEOS
GO TO 50                         LTEOS
40 ECOLD = (ECMAT(200) + P0*((AK+ 2.)*(E/D1)**AK - AK*(E/D1)**(AK+ 1.))    LTEOS
1 - 2.)/(D1*AK))/R0               LTEOS
50 RETURN                          LTEOS
END                               LTEOS
50 RETURN                          LTEOS
END                               LTEOS
SUBROUTINE PDPCAL(T0,E,PRES,PRESP,PRESPP,I5)                29AP72
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q  COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2                 COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0                           21AP72
COMMON ECMAT(200),ETAMAT(200),A,B1,B2,      C1,C2,C3,C5,C4,D1,AK, 21AP72
1 EREF,TREF,SAVE(50), P0,THETIN,RHOIN,PTOT,ETOT,RCOLD     21AP72
DIMENSION AP(20),P(3,3),RP(3),D(3),TEMP(3),IROW(3)        LTEOS
C
C FINDS THE FIRST AND SECOND DERIVATIVES OF THE PRESSURE WITH 29AP72
C RESPECT TO DENSITY AT A CONSTANT TEMPERATURE             29AP72
C
C PRESPP = 0.                                              29AP72
IF(I5 .EQ. 0) GO TO 5                                     29AP72
IF(T0 .NE. TREF) GO TO 1                                  LTEOS
IF(ABS((E-EREF)/E) .LT. .07) GO TO 5                    LTEOS
1 I1 = 1                                              LTEOS
TREF = T0                                         LTEOS
EREF = E                                           LTEOS
DO 3 I = 1,3                                         LTEOS
AI = I                                           LTEOS
EP = E*(1. + (AI- 2.)*.07)                         LTEOS
P(I,1) = 1.                                         LTEOS
P(I,2) = EP                                         LTEOS
P(I,3) = EP**2                                       LTEOS
DO 2 J = 1,2                                         LTEOS
AJ = J                                           LTEOS
B = EP*(1. + (AJ - 1.5)*.001)*R0                   21AP72
CALL EOS(1,B,T0,AP(I1),ETOT)                         21AP72
2 I1 = I1 + 1                                         LTEOS

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3  RP(I) = (AP(I1-1) - AP(I1-2))/(.001*EP)          LTEOS
   CALL MATINV(P,3,3,IROW,TEMP)                      LTEOS
   CALL MATMPY(3,3,1,P,3,RP,3,D,3)                  LTEOS
5  DO 6 I = 1,3                                     LTEOS
   AI = I                                         LTEOS
   EP = E*(1. + .0005*(AI-2.))                   LTEOS
   CALL PTHERM(EP,T0,PT,PTP,ET,ETP,ST,STP,SI)    LTEOS
   CALL COLD(EP,PCOLD,PPCOLD,ECOLD,EPCOLD)        LTEOS
   AP(I) = PTP + PPCOLD                           LTEOS
   B = EP*R0                                      29AP72
   CALL EOS(1,B,T0,AP(17+I),DELEEE)              29AP72
6  AP(I+3) = PT + PCOLD + AP(17+I)                29AP72
   IF(I5 .EQ. 0) GO TO 7                         29AP72
   PRESPP = D(2) + 2.*E*D(3) + (AP(3) - AP(1))/(.001*E) 29AP72
7  PRESPP = AP(2) + (AP(20) - AP(18))/(.001*E)    29AP72
   PRES = AP(5)                                    29AP72
   RETURN                                         LTEOS
   END                                             LTEOS
   SUBROUTINE PTHERM(E,T0,PT,PTP,ET,ETP,ST,STP,SI)  LTEOS
   COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q COM1
1  N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2      COM1
   COMMON ATMWT,ATMNO,H4,GAMMA,RO                 21AP72
   COMMON ECMAT(200),ETAMAT(200),A,B1,B2,           C1,C2,C3,C5,C4,D1,AK, 21AP72
   1     EREF,TREF,SAVE(50),    P0,THETIN,RHOIN,PTOT,ETOT,RCOLD      21AP72
C
C   FOR INPUT TEMPERATURE AND DENSITY, CALCULATES THE THERMAL NUCLEAR EXPLA
C   CONTRIBUTION TO THE PRESSURE AND ENERGY             EXPLA
C                                                       EXPLA
C                                                       EXPLA
C
C   IPRES = 0                                         EXPLA
2  B = .9653/ATMWT                                  LTEOS
   IF(E .LT. 1.) GO TO 1                            LTEOS
   GAMPP = GAMMA/E + .6666667*((E-1.)/E)**2       LTEOS
   GAMPP = -GAMMA/E**2 + 4.*((E-1.)/(3.*E**3))    LTEOS
   DEBYE = H4*EXP((GAMMA/E - (3.*E-1.)/(3.*E**2))*(E-1.))*E**.6666667  LTEOS
   DEBYEP = 2.*DEBYE/(3.*E)+DEBYE*(GAMMA/E**2+2.*((E-1.)/E)/(3.*E**3))  LTEOS
   GO TO 10                                         LTEOS
1  IF(E .GT. 1.E-10) GO TO 5                        LTEOS
   ET = 1.5*B*T0                                    LTEOS
   ETP = 0.                                         LTEOS
   PT = R0*E*B*T0                                  LTEOS
   PTP = R0*B*T0                                   LTEOS
   T = H4*EXP(1.5 - 2.*GAMMA)                      LTEOS
   SI = .018596*(R0/ATMWT)**(2./3.)*T0*T/(ATMWT*E**(4./3.))  LTEOS
   ST = -B*(ALOG(.018596*T0/ATMWT)**1.5*R0*E/ATMWT/T0**3) - 2.5*T0  LTEOS
   STP = -B/E*T0                                    LTEOS
   GO TO 20                                         LTEOS
5  G5 = GAMMA - 1.                                    LTEOS
   G6 = 1. - 2.*GAMMA                               LTEOS
   GAMPP = E*(G5 + G6*(E-1.))+1.                  LTEOS
   GAMPP = G5 + G6*(2.*E - 1.)                     LTEOS
   DEBYE = H4*E*EXP(((3.*GAMMA-2. )+ .5*(1.-2.*GAMMA)*(E+1.))*(E-1.))  LTEOS
   DEBYEP = DEBYE/E + DEBYE*(3.*GAMMA-2. + E*(1.-2.*GAMMA))  LTEOS
10  SI = .018596*(T0/DEBYE**2)*(E*R0/ATMWT)**.6666667/ATMWT  LTEOS

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W = 2. *SI/(3. *E) - 2. *SI*DEBYEP/DEBYE          LTEOS
ET = 1. 5*B*T0*(2. + SI)/(1. + SI)                LTEOS
ETP = - ET*W/((1. + SI)*(2. + SI))               LTEOS
PT = R0*E*B*T0*(3. *GAMP + SI)/(1. + SI)          LTEOS
PTP = PT/E-PT*W/(1. + SI)+ PT*(3. *GAMPP+ W)/(3. *GAMP+ SI)  LTEOS
ST=- T0*B*(3. *ALOG(DEBYE/T0)- 4. + 1. 5*ALOG(1. + SI) + 1. 5*SI/(1. + SI))  LTEOS
STP = - B*(3. *DEBYEP/DEBYE+ 3. *W/(1. + SI)- 3. *SI*W/(2. *(1. + SI)**2))*T0  LTEOS
20 IF(IPRES .GT. 0) GO TO 30                      LTEOS
IPRES = IPRES + 1                                LTEOS
S1 = SI                                         LTEOS
ET1 = ET                                         LTEOS
PT1 = PT                                         LTEOS
ST1 = ST                                         LTEOS
ETP1 = ETP                                        LTEOS
PTP1 = PTP                                        LTEOS
STP1 = STP                                        LTEOS
T1 = T0                                         LTEOS
T0 = .01                                         LTEOS
GO TO 2                                         LTEOS
30 T0 = T1                                         LTEOS
SI = S1                                         LTEOS
ET = ET1 - ET                                     LTEOS
PT = PT1 - PT                                     LTEOS
ST = ST1 - ST                                     LTEOS
PTP = PTP1 - PTP                                   LTEOS
ETP = ETP1 - ETP                                   LTEOS
STP = STP1 - STP                                   LTEOS
RETURN
END
SUBROUTINE COLCOFS(S,C0,PUPPER,U)
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2        COM1
COMMON ATMWT,ATMNO,H4,GAMMA,R0
COMMON ECMAT(200),ETAMAT(200),A,B1,B2,           C1,C2,C3,C5,C4,D1,AK,
1 EREF,TREF,SAVE(50),   P0,THETIN,RHOIN,PTOT,ETOT,RCOLD  21AP72
DIMENSION RP(3),P(3,3),D(3),TEMP(3),IROW(3),PTEST(10),ETEST(10)
EQUIVALENCE (ECMAT,TEMP),(ETAMAT,IROW)
C
C      SETS UP THE CONSTANTS FOR THE T=0 CURVE (MODIFIED TO TAKE INTO
C      ACCOUNT LOW TEMPERATURE CONTRIBUTIONS)          EXPLA
C
D1 = S/(S+ 1.)                                     LTEOS
RCOLD = R0                                         4APR72
RSAVE = R0                                         4APR72
PSAVE = P0                                         4APR72
NTRY = 1                                           4APR72
2 R0 = RCOLD                                       4APR72
AO = PUPPER                                       LTEOS
B0 = 0.01*R0*C0**2                               LTEOS
D0 = .02*R0*C0**2*(2. *S - 1.)                  LTEOS
THIRD = 1./3.                                      LTEOS
TTHIRD = 2. *THIRD                                LTEOS

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C***** PRESSURE CALCULATION FOR ETA GT. 1 *****
A = B0 LTEOS
B1 = 1.25*ALOG(A0/(3100.*B0)) LTEOS
B2 = B1 LTEOS
DO 5 J = 1,100 LTEOS
P(1,1) = 3125.*EXP(.8*B1) - 25.*EXP(.8*B2) LTEOS
P(2,1) = 1. + B1/3. - B2/3. LTEOS
P(3,1) = 1.333333 + TTHIRD*B1 + B1**2/9. - B2**2/9. LTEOS
RP(1) = A0 - P(1,1)*A LTEOS
RP(2) = B0 - P(2,1)*A LTEOS
RP(3) = D0 - P(3,1)*A LTEOS
IF (ABS(RP(1)/A0) .GT. .00001 ) GO TO 1 LTEOS
IF(ABS(RP(2)/B0) .GT. .00001) GO TO 1 LTEOS
IF(ABS(RP(3)/D0) .LE. .00001) GO TO 15 LTEOS
1 P(1,2) = 2500.*A*EXP(.8*B1) LTEOS
P(2,2) = A/3. LTEOS
P(3,2) = A*(TTHIRD + 2.*B1/9.) LTEOS
P(1,3) = -20.*A*EXP(.8*B2) LTEOS
P(2,3) = -A/3. LTEOS
P(3,3) = -2.*B2*A/9. LTEOS
CALL MATINV(P,3,3,IROW,TEMP) LTEOS
CALL MATMPY(3,3,1,P,3,RP,3,D,3) LTEOS
A = A + D(1) LTEOS
B1 = B1 + D(2) LTEOS
5 B2 = B2 + D(3) LTEOS
WRITE (9,10) LTEOS
10 FORMAT(3X,*HAVE DONE 100 ITERATIONS, CAN NOT CONVERGE*) LTEOS
GO TO 50 LTEOS
15 GAMMA = (D0 + TTHIRD*B0)/(2.*B0) - .3333333333 LTEOS
B = R0*D1 4APR72
CALL EOS(1,B,.02,DELPE,DELEE) 4APR72
CALL PTHERM(D1,.02,PT,PTP,ET,ETP,ST,STP,SI) 4APR72
DELPEP = DELPE + PT 4APR72
P0 = PSAVE - DELPEP 4APR72
R0 = RSAVE 4APR72
CALL EOS(1,RSAVE,.02,DELPE,DELEE) 4APR72
CALL PTHERM(1,.02,PT,PTP,ET,ETP,ST,STP,SI) 4APR72
DELPEP = DELPE + PT 4APR72
R0 = RCOLD 4APR72
C***** PRESSURE CALCULATION FOR S/(S+1) LT. ETA LT. 1 *****
D2 = 1. - D1**THIRD LTEOS
C1 = -P0/(D1*D1**THIRD*D2) LTEOS
C2 = C1*(5.*D1**THIRD - 4.)/(D1**THIRD*D2) LTEOS
C3 = (3.*B0 - C1 - C2*D2)/D2**2 LTEOS
G1 = 9.*D0 - 6.*C1 - (2.+6.*D2)*C2 - (6.*D2**2+4.*D2)*C3 LTEOS
C4 = G1/(2.*D2**2) LTEOS
G1 = 20.*R0*U - 30.*C1 - (30.*D2-20.)*C2 - (15.-40.*D2+30.*D2**2)*C3 LTEOS
C5 = (G1-(30.*D2-12.-20.*D2**2)*C4)/(10.-24.*D2+15.*D2**2) LTEOS
C***** PRESSURE CALCULATION FOR ETA LT. S/(S+1) *****
IF(NTRY .GT. 1) GO TO 105 4APR72
E = 1. 4APR72
NTRY = 2 4APR72
DO 100 I = 1,10 4APR72
CALL COLD(E,PTEST(I),PPCOLD,ECOLD,EPCOLD) 4APR72

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ETEST(I) = E                                4APR72
IF(- PTEST(I) . LT. DELPEP) GO TO 100      4APR72
ITRY = I                                     4APR72
GO TO 106                                    4APR72
100 E = E - .005                            4APR72
PRINT 104                                    4APR72
104 FORMAT(* DID NOT BRACKET CROSSPOINT*)   4APR72
STOP                                         4APR72
106 ETA = ETEST(ITRY)+(ETEST(ITRY-1)-ETEST(ITRY))*(- PTEST(ITRY)-DELPEP) 4APR72
1  /(- PTEST(ITRY)+ PTEST(ITRY-1))          4APR72
RCOLD = R0/ETA                               4APR72
GO TO 2                                      4APR72
105 E = RSAVE/R0                             4APR72
CALL COLD(E,PCOLD,PPCOLD,ECOLD,EPCOLD)       4APR72
IF(ABS((PCOLD+ DELPEP)/DELPEP) . LT. 1.E-6) GO TO 150 4APR72
RCOLD = RSAVE*RCOLD/(RSAVE- RCOLD*(PCOLD+ DELPEP)/PPCOLD) 4APR72
GO TO 2                                      4APR72
150 F = 0.                                    4APR72
G1 = (1. - D1)/800.                         LTEOS
D2 = 1.                                       LTEOS
DO 25 I = 1,200                            LTEOS
DO 20 J = 1,4                           LTEOS
AJ = J                                       LTEOS
E = D2 - G1*AJ                            LTEOS
E1 = 1. - E**THIRD                         LTEOS
E2 = E**THIRD - D1**THIRD                  LTEOS
IF(E . NE. 0) GO TO 19                      LTEOS
ECMAT(I) = F                                LTEOS
ETAMAT(I) = E                                LTEOS
GO TO 25                                     LTEOS
19 T1 = E1*(C1 + E2*(C2 + E2*(C3 - E1*(C4 - C5*E1))))  LTEOS
20 F = F + G1*T1/E**TTHIRD                  LTEOS
ECMAT(I) = F - G1*T1/(2.*E**TTHIRD)        LTEOS
ETAMAT(I) = E                                LTEOS
25 D2 = E                                     LTEOS
AK = -2.*P0/(D1*(R0*U - ECMAT(200)))      LTEOS
PAK = R0*U - ECMAT(200)                     29AP72
D2 = D1/400.                                 LTEOS
DO 30 I = 1,400                            LTEOS
AJ = I                                       LTEOS
E = D2*AJ                                    LTEOS
T1 = P0*(AK+2. - (AK+1.)*E/D1)*(E/D1)**(AK+1.)/E**2  LTEOS
30 F = F - T1*D2                           LTEOS
UINT = (F + T1*D2/2.)/R0                    LTEOS
IF(ABS((U - UINT)/U) . GT. .001) WRITE(9,31) U,UINT  LTEOS
31 FORMAT(3X,*THE COHESIVE ENERGY *,E13.6,*DOES NOT AGREE WELL WITH  LTEOS
1 THE CALCULATED ENERGY *,E13.6)            LTEOS
50 R0 = RSAVE                                4APR72
RETURN                                     4APR72
END                                         LTEOS
SUBROUTINE PGCAL(I5,EP,T0,PTOTA,PPTOT,ETOTA,GTOT,GPTOT) 29AP72
COMMON /BLK/ AO,A1,E3,E4,F1,R,R2,S2,TO,X,Y,Z,Z9,Z10,Q(8),J1,N,QN,Q
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2           COM1
1 N3,TO1,Q3(7),RQB,TO32,ITRAN,Z11,Y5,FNZR2           COM1

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COMMON ATMWT,ATMNO,H4,GAMMA,R0 21AP72
COMMON ECMAT(200),ETAMAT(200),A,B1,B2, C1,C2,C3,C5,C4,D1,AK, 21AP72
1 EREF,TREF,SAVE(50), P0,THETIN,RHOIN,PTOT,ETOT,RCOLD 21AP72
DIMENSION AP(5) 29AP72

C 29AP72
C CALCULATES THE PRESSURE, INTERNAL ENERGY, AND GIBBS FREE ENERGY 29AP72
C AND FIRST DERIVATIVE WITH RESPECT TO DENSITY OF ABOVE FOR INPUT 29AP72
C TEMPERATURES AND DENSITIES 29AP72
C 29AP72
IF(I5 . EQ. 0) GO TO 11 29AP72
DO 10 I = 1,2 LTEOS
AI = I LTEOS
B = EP*(1. + (AI - 1.5)*.001)*R0 29AP72
CALL EOS(0,B,.01,PLOWER,ELOWER) LTEOS
GUN = 0. 29AP72
GUN = FNZR2*E4*.01 29AP72
2 CALL EOS(0,B,T0,PUPPER,EUPPER) LTEOS
E = B/R0 29AP72
F = PSI(E,T0) 29AP72
AP(I) = (PUPPER - PLOWER)*F 29AP72
10 AP(I+2) = -(FNZR2*E4*T0 - GUN)*F 29AP72
11 B = EP*R0 29AP72
CALL PTHERM(EP,T0,PT,PTP,ET,ETP,ST,STP,SI) 29AP72
CALL COLD(EP,PCOLD,PPCOLD,ECOLD,EPCOLD) 29AP72
CALL EOS(1,B,T0,DELPE,DELEE) 29AP72
PTOTA = PT + PCOLD + DELPE 29AP72
PPTOT = PTP + PPCOLD + (AP(2) - AP(1))/(.001*EP) 29AP72
ETOTA = ET + ECOLD + DELEE 29AP72
GTOT = ET + ECOLD - ST + (PT+PCOLD)/(R0*EP) + (AP(4)+AP(3))/2. * 29AP72
1 .9653/ATMW 29AP72
GPTOT = ETP - STP - PT/(R0*EP**2) + (PTP+PPCOLD)/(R0*EP) + (AP(4)- 29AP72
1 AP(3))/(.001*EP)*.9653/ATMW 29AP72
RETURN LTEOS
END LTEOS
FUNCTION EPIN(AX) LTEOS
DIMENSION MESG(6) LTEOS
DATA P0/1.0/,P1/0.16515516520352/,P2/0.23785541396286E-1/, LTEOS
1 P3/0.92333053076239E-3/,P4/0.9713386753293E-5/, LTEOS
2 Q0/1.0/,Q1/0.4151551652034/,Q2/0.72018777145175E-1/, LTEOS
3 Q3/0.62805155999224E-2/,Q4/0.23666563141677E-3/,(MESG(I),I=1,6)/, LTEOS
4 48HE1(X) X . LE. 0 NOT ALLOWED RESULT=LARGEST NUMBER/, LTEOS
5 OMEGA/1.E256/ LTEOS

C EXPLA
C EXPONENTIAL INTEGRAL EXPLA
C EXPLA
X=AX LTEOS
IF (X. GT. 1.0)GO TO 30 LTEOS
IF(X. LE. 0.0) GO TO 20 LTEOS
10 E1=X*(P0+ X*(P1+ X*(P2+ X*(P3+ X*P4))))/(Q0+ X*(Q1+ X*(Q2+ X*(Q3+ X*Q4)))) LTEOS
1 - ALOG(X)-0.57721566490153 LTEOS
RETURN LTEOS
20 CALL LABRT(1,MESG,0) LTEOS
E1=OMEGA LTEOS

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RETURN	LTEOS
30 E1=GAMMA(0.,X)	LTEOS
EPIN = E1	LTEOS
RETURN	LTEOS
END	LTEOS